AT25080B and AT25160B

SPI Serial EEPROMs 8K (1,024 x 8) and 16K (2,048 x 8)

DATASHEET

Features

Atmel

- Serial Peripheral Interface (SPI) Compatible
- Supports SPI Modes 0 (0,0) and 3 (1,1)
 - Datasheet Describes Mode 0 Operation
- Low-voltage and Standard-voltage Operation
 1.8 (V_{CC} = 1.8V to 5.5V)
- 20MHz Clock Rate (5V)
- 32-byte Page Mode
- Block Write Protection
 - Protect 1/4, 1/2, or Entire Array
- Write Protect (WP) Pin and Write Disable Instructions for Both Hardware and Software Data Protection
- Self-timed Write Cycle (5ms max)
- High Reliability
 - Endurance: 1,000,000 Write Cycles
 - Data Retention: 100 Years
- Green (Pb/Halide-free/RoHS Compliant) Packaging Options
- Die Sales: Wafer Form, Tape and Reel, and Bumped Wafers

Description

The Atmel[®] AT25080B/160B provides 8,192/16,384 bits of Serial Electrically-Erasable Programmable Read-Only Memory (EEPROM) organized as 1,024/2,048 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operation are essential. The AT25080B/160B is available in space-saving 8-lead JEDEC SOIC, 8-lead TSSOP, 8-pad UDFN, 8-pad XDFN, 8-ball VFBGA, and 8-ball WLCSP packages.

The AT25080B/160B is enabled through the Chip Select pin (\overline{CS}) and accessed via a 3-wire interface consisting of Serial Data Input (SI), Serial Data Output (SO), and Serial Clock (SCK). All programming cycles are completely self-timed, and no separate erase cycle is required before write.

Block Write protection is enabled by programming the status register with one of four blocks of write protection. Separate program enable and program disable instructions are provided for additional data protection. Hardware data protection is provided via the $\overline{\text{WP}}$ pin to protect against inadvertent write attempts to the status register. The $\overline{\text{HOLD}}$ pin may be used to suspend any serial communication without resetting the serial sequence.

1. Pin Configurations and Pinouts

Table 1. Pin Configurations

| Pin Name | Function |
|-----------------|-----------------------|
| CS | Chip Select |
| GND | Ground |
| HOLD | Suspends Serial Input |
| SCK | Serial Data Clock |
| SO | Serial Data Output |
| SI | Serial Data Input |
| WP | Write Protect |
| V _{CC} | Power Supply |

(Top View) CS 10 8 10 V_{CC} SO 12 7 10 HOLD WP 3 6 10 SCK GND 14 5 10 SI

8-lead SOIC

| 8-pad UDFN/XDFN (Top View) | | | | | |
|-------------------------------|-----------------------|--------------------------|--------------------------------------|--|--|
| CS SO WP GND | 1 2 3 2 4 | 8 [7 [6 [5 [| V _{CC} HOLD SCK SI | | |



⊐ si

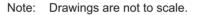
5



8-ball WLSCP (Top View)

GND [





2. Absolute Maximum Ratings*

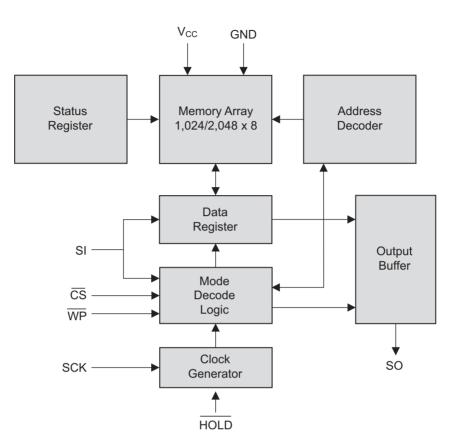
| Operating Temperature $\ldots \ldots55^\circ C$ to +125°C |
|---|
| Storage Temperature |
| Voltage on Any Pin with Respect to Ground |
| Maximum Operating Voltage 6.25V |
| DC Output Current |

*Notice: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



3. Block Diagram

Figure 3-1. Block Diagram





4. Memory Organization

4.1 Pin Capacitance

Table 4-1.Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^{\circ}C$, f = 1.0MHz, $V_{CC} = +5.0V$ (unless otherwise noted).

| Symbol | Test Conditions | Max | Units | Conditions |
|------------------|--|-----|-------|-----------------------|
| C _{OUT} | Output Capacitance (SO) | 8 | pF | V _{OUT} = 0V |
| C _{IN} | Input Capacitance (\overline{CS} , SCK, SI, \overline{WP} , \overline{HOLD}) | 6 | pF | V _{IN} = 0V |

Note: 1. This parameter is characterized and is not 100% tested.

4.2 DC Characteristics

Table 4-2. DC Characteristics

Applicable over recommended operating range from $T_{AI} = -40^{\circ}$ C to $+85^{\circ}$ C, $V_{CC} = 1.7$ V to 5.5V (unless otherwise noted).

| Symbol | Parameter | Test Condition | | Min | Тур | Max | Units |
|--------------------------------|---------------------|--|---|-----------------------|-------|-----------------------|-------|
| V _{CC1} | Supply Voltage | | 1.8 | | 5.5 | V | |
| V _{CC2} | Supply Voltage | | | 2.5 | | 5.5 | V |
| V _{CC3} | Supply Voltage | | | 4.5 | | 5.5 | V |
| I _{CC1} | Supply Current | V _{CC} = 5.0V at 20MH SO = Open and Re | | | 7.5 | 10.0 | mA |
| I _{CC2} | Supply Current | V _{CC} = 5.0V at 20MH SO = Open, Read, | | | 4.0 | 10.0 | mA |
| I _{CC3} | Supply Current | V _{CC} = 5.0V at 5MHz SO = Open, Read, | | | 4.0 | 6.0 | mA |
| I _{SB1} | Standby Current | $V_{CC} = 1.8V, \overline{CS} = V$ | cc | | < 0.1 | 6.0 ⁽²⁾ | μA |
| I _{SB2} | Standby Current | V_{CC} = 2.5V, \overline{CS} = V | V_{CC} = 2.5V, \overline{CS} = V_{CC} | | | 7.0 ⁽²⁾ | μA |
| I _{SB3} | Standby Current | $V_{CC} = 5.0V, \overline{CS} = V_{CC}$ | | | 2.0 | 10.0 ⁽²⁾ | μA |
| I _{IL} | Input Leakage | V_{IN} = 0V to V_{CC} | | -3.0 | | 3.0 | μA |
| I _{OL} | Output Leakage | $V_{IN} = 0V$ to V_{CC} , T_{AC} | _c = 0°C to 70°C | -3.0 | | 3.0 | μA |
| V _{IL} ⁽¹⁾ | Input Low-voltage | | | -0.6 | | V _{CC} x 0.3 | V |
| V _{IH} ⁽¹⁾ | Input High-voltage | | | V _{CC} x 0.7 | | V _{CC} + 0.5 | V |
| V _{OL1} | Output Low-voltage | | I _{OL} = 3.0mA | | | 0.4 | V |
| V _{OH1} | Output High-voltage | $3.6V \le V_{CC} \le 5.5V$ | I _{OH} = -1.6mA | V _{CC} - 0.8 | | | V |
| V _{OL2} | Output Low-voltage | $1.8V \le V_{CC} \le 3.6V$ | I _{OL} = 0.15mA | | | 0.2 | V |
| V _{OH2} | Output High-voltage | $1.00 \ge 0_{CC} \ge 3.00$ | I _{OH} = -100μA | V _{CC} - 0.2 | | | V |

Notes: 1. V_{IL} min and V_{IH} max are reference only and are not tested.

2. Worst case measured at 85°C.



4.3 AC Characteristics

Table 4-3. AC Characteristics

Applicable over recommended operating range from T_{AI} = -40°C to +85°C, V_{CC} = as specified, CL = 1 TTL gate and 100pF (unless otherwise noted).

| Symbol | Parameter | Voltage | Min | Мах | Units |
|------------------|---------------------|--|-----------------|----------------|-------|
| f _{scк} | SCK Clock Frequency | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 0 0 0 | 20 10 5 | MHz |
| t _{RI} | Input Rise Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | | 2 2 2 | μs |
| t _{FI} | Input Fall Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | | 2 2 2 | μs |
| t _{wH} | SCK High Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 20 40 80 | | ns |
| t _{wL} | SCK Low Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 20 40 80 | | ns |
| t _{cs} | CS High Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 25 50 100 | | ns |
| t _{css} | CS Setup Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 25 50 100 | | ns |
| t _{csh} | CS Hold Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 25 50 100 | | ns |
| t _{su} | Data In Setup Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 5 10 20 | | ns |
| t _H | Data In Hold Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 5 10 20 | | ns |
| t _{HD} | HOLD Setup Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 5 10 20 | | |
| t _{cD} | HOLD Hold Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 5 10 20 | | ns |
| t _v | Output Valid | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 0 0 0 | 20 40 80 | ns |



Table 4-3. AC Characteristics (Continued)

Applicable over recommended operating range from T_{AI} = -40°C to +85°C, V_{CC} = as specified, CL = 1 TTL gate and 100pF (unless otherwise noted).

| Symbol | Parameter | Voltage | Min | Мах | Units |
|--------------------------|-----------------------|--|-------------|-----------------|-----------------|
| t _{HO} | Output Hold Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 0 0 0 | | ns |
| t _{LZ} | HOLD to Output Low Z | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | 0 0 0 | 25 50 100 | ns |
| t _{HZ} | HOLD to Output High Z | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | | 40 80 200 | ns |
| t _{DIS} | Output Disable Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | | 40 80 200 | ns |
| t _{wc} | Write Cycle Time | 4.5 to 5.5 2.5 to 5.5 1.8 to 5.5 | | 5 5 5 | ms |
| Endurance ⁽¹⁾ | 3.3V, 25°C, Page Mode | | 1M | | Write Cycles |

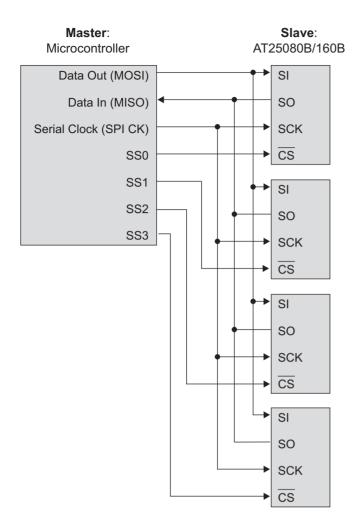
Note: 1. This parameter is characterized and is not 100% tested.



5. Serial Interface Description

| Interface | Description |
|----------------------|---|
| Master | The device that generates the Serial Clock. |
| Slave | Because the Serial Clock pin (SCK) is always an input, the AT25080B/160B always operates as a slave. |
| Transmitter/Receiver | The AT25080B/160B has separate pins designated for data transmission (SO) and reception (SI). |
| MSB | The Most Significant Bit (MSB) is the first bit transmitted and received. |
| Serial Opcode | After the device is selected with \overline{CS} going low, the first byte will be received. This byte contains the opcode that defines the operations to be performed. |
| Invalid Opcode | If an invalid opcode is received, no data will be shifted into the AT25080B/160B, and the serial output pin (SO) will remain in a high-impedance state until the falling edge of \overline{CS} is detected. This will reinitialize the serial communication. |
| Chip Select | The AT25080B/160B is selected when the \overline{CS} pin is low. When the device is not selected, data will not be accepted via the SI pin, and the Serial Output pin (SO) will remain in a high-impedance state. |
| Hold | The $\overline{\text{HOLD}}$ pin is used in conjunction with the $\overline{\text{CS}}$ pin to select the AT25080B/160B. When the device is selected and a serial sequence is underway, Hold can be used to pause the serial communication with the master device without resetting the serial sequence. To pause, the $\overline{\text{HOLD}}$ pin must be brought low while the SCK pin is low. To resume serial communication, the $\overline{\text{HOLD}}$ pin is brought high while the SCK pin is low (SCK may still toggle during Hold). Inputs to the SI pin will be ignored while the SO pin is in the high impedance state. |
| Write Protect | The Write Protect pin (\overline{WP}) allows normal Read and Write operations when held high. When the WP pin is brought low and WPEN bit is one, all write operations to the status register are inhibited. When the \overline{WP} is low while \overline{CS} is low, it will interrupt a Write to the status register. If the internal write cycle has already been initiated, \overline{WP} going low will have no effect on any Write operation to the status register. The \overline{WP} pin function is blocked when the WPEN bit in the status register is zero. This will allow the user to install the AT25080B/160B in a system with the \overline{WP} pin tied to ground, and it will be able to write to the status register. All \overline{WP} pin functions are enabled when the WPEN bit is set to one. |

Table 5-1. Serial Interface Description





6. Functional Description

The AT25080B/160B is designed to interface directly with the synchronous Serial Peripheral Interface (SPI) of the 6805 and 68HC11 microcontroller series.

The AT25080B/160B utilizes an 8-bit instruction register. The list of instructions and their operation codes are contained in the table below. All instructions, addresses, and data are transferred with the MSB first and starts with a high-to-low CS transition.

| Instruction Name | Instruction Format | Operation |
|------------------|--------------------|-----------------------------|
| WREN | 0000 X110 | Set Write Enable Latch |
| WRDI | 0000 X100 | Reset Write Enable Latch |
| RDSR | 0000 X101 | Read Status Register |
| WRSR | 0000 X001 | Write Status Register |
| Read | 0000 X011 | Read Data from Memory Array |
| Write | 0000 X010 | Write Data to Memory Array |

Table 6-1. Instruction Set for the AT25080B/160B

Write Enable (WREN): The device will power up in the Write Disable state when V_{CC} is applied. All programming instructions must therefore be preceded by a Write Enable instruction.

Write Disable (WRDI): To protect the device against inadvertent writes, the WRDI instruction disables all programming modes. The WRDI instruction is independent of the status of the \overline{WP} pin.

Read Status Register (RDSR): The RDSR instruction provides access to the status register. The Ready/Busy and Write Enable status of the device can be determined by the RDSR instruction. Similarly, the Block Write Protection bits indicate the extent of protection employed. These bits are set by using the WRSR instruction.

Table 6-2. Status Register Format

| Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
|-------|-------|-------|-------|-------|-------|-------|-------|
| WPEN | Х | Х | Х | BP1 | BP0 | WEN | RDY |

Table 6-3. Read Status Register Bit Definition

| Bit | Definition |
|--------------|--|
| Bit 0 (RDY) | If zero, it indicates the device is ready. |
| | If one, it indicates the write cycle is in progress. |
| | If zero, it indicates the device is <i>not</i> write enabled. |
| Bit 1 (WEN) | If one, it indicates the device is write enabled. |
| Bit 2 (BP0) | See Table 6-4 on page 10. |
| Bit 3 (BP1) | See Table 6-4. |
| Bits 4 to 6 | These are zeros when device is not in an internal write cycle. |
| Bit 7 (WPEN) | See Table 6-5 on page 10 |
| Bits 0 to 7 | These are ones during an internal write cycle. |

Write Status Register (WRSR): The WRSR instruction allows the user to select one of four levels of protection. The AT25080B/160B is divided into four array segments. One-quarter (1/4), one-half (1/2), or all of the memory segments can be protected. Any of the data within any selected segment will be read-only. The block write protection levels and corresponding status register control bits are shown in Table 6-4.

The three bits BP0, BP1, and WPEN are nonvolatile cells that have the same properties and functions as the regular memory cells (e.g., WREN, t_{WC} , RDSR).

| | Status Re | gister Bits | Array Addres | ses Protected |
|--------|-----------|-------------|--------------|---------------|
| Level | BP1 | BP0 | AT25080B | AT25160B |
| 0 | 0 | 0 | None | None |
| 1(1/4) | 0 | 1 | 0300 – 03FF | 0600 – 07FF |
| 2(1/2) | 1 | 0 | 0200 – 03FF | 0400 – 07FF |
| 3(All) | 1 | 1 | 0000 – 03FF | 0000 – 07FF |

Table 6-4. Block Write Protect Bits

The WRSR instruction allows the user to enable or disable the Write Protect (\overline{WP}) pin through the use of the Write Protect Enable (WPEN) bit. Hardware Write protection is enabled when the \overline{WP} pin is low and the WPEN bit is one. Hardware Write protection is disabled when either the \overline{WP} pin is high or the WPEN bit is zero. When the device is hardware write protected, writes to the status register, including the block protect bits and the WPEN bit, and the block-protected sections in the memory array are disabled. Writes are only allowed to sections of the memory that are not block-protected.

Note: When the WPEN bit is Hardware Write protected, it cannot be changed back to zero as long as the WP pin is held low.

| WPEN | WP | WEN | Protected Blocks | Unprotected Blocks | Status Register |
|------|------|-----|---------------------|-----------------------|--------------------|
| 0 | Х | 0 | Protected | Protected | Protected |
| 0 | Х | 1 | Protected | Writeable | Writeable |
| 1 | Low | 0 | Protected | Protected | Protected |
| 1 | Low | 1 | Protected | Writeable | Protected |
| Х | High | 0 | Protected | Protected | Protected |
| Х | High | 1 | Protected | Writeable | Writeable |

Table 6-5. WPEN Operation



Read Sequence (Read): Reading the AT25080B/160B via the Serial Output (SO) pin requires the following sequence. After the \overline{CS} line is pulled low to select a device, the read opcode is transmitted via the SI line followed by the byte address to be read (A15 to A0, see Table 6-6). Upon completion, any data on the SI line will be ignored. The data (D7 to D0) at the specified address is then shifted out onto the SO line. If only one byte is to be read, the \overline{CS} line should be driven high after the data comes out. The read sequence can be continued since the byte address is automatically incremented and data will continue to be shifted out. When the highest address is reached, the address counter will roll-over to the lowest address allowing the entire memory to be read in one continuous read cycle.

Write Sequence (Write): In order to program the AT25080B/160B, two separate instructions must be executed. First, the device *must be write enabled* via the WREN instruction, and then a Write instruction can be executed. The address of the memory location(s) to be programmed must be outside the protected address field location selected by the block write protection level. During an internal write cycle, all commands will be ignored except the RDSR instruction.

A Write instruction requires the following sequence. After the \overline{CS} line is pulled low to select the device, the Write opcode is transmitted via the SI line followed by the byte address (A15 to A0) and the data (D7 to D0) to be programmed (see Table 6-6). Programming will start after the \overline{CS} pin is brought high. The low-to-high transition of the \overline{CS} pin must occur during the SCK low-time immediately after clocking in the D0 (LSB) data bit.

The Ready/Busy status of the device can be determined by initiating a RDSR instruction. If Bit 0 is one, the write cycle is still in progress. If Bit 0 is zero, the write cycle has ended. Only the RDSR instruction is enabled during the write programming cycle.

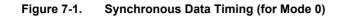
The AT25080B/160B is capable of a 32-byte Page Write operation. After each byte of data is received, the five low-order address bits are internally incremented by one; the high-order bits of the address will remain constant. If more than 32 bytes of data are transmitted, the address counter will roll-over and the previously written data will be overwritten. The AT25080B/160B is automatically returned to the write disable state at the completion of a write cycle.

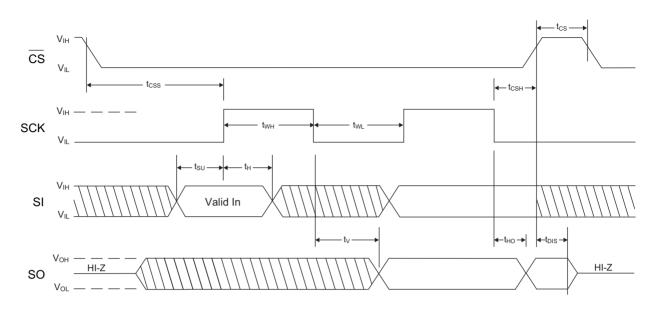
Note: If the device is *not* write-enabled (WREN), the device will ignore the Write instruction and will return to the standby state when \overline{CS} is brought high. A new \overline{CS} falling edge is required to reinitiate the serial communication.

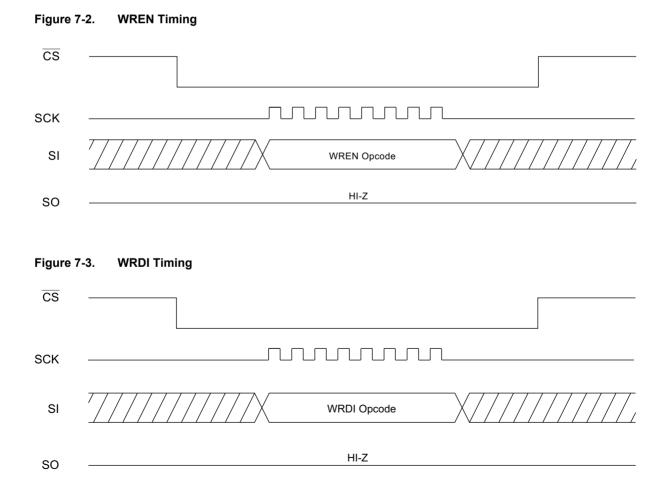
| Address | AT25080B | AT25160B | |
|-----------------|-----------------------------------|-----------------------------------|--|
| A _N | $A_{9} - A_{0}$ | A ₁₀ - A ₀ | |
| Don't Care Bits | A ₁₅ - A ₁₀ | A ₁₅ – A ₁₁ | |

Table 6-6. Address Key

7. Timing Diagrams

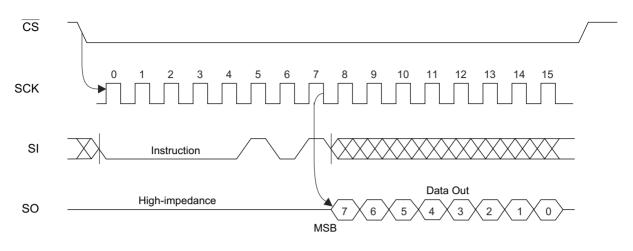


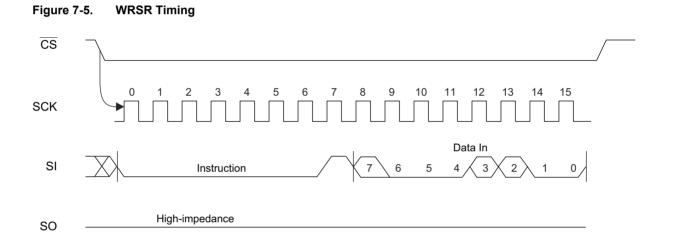






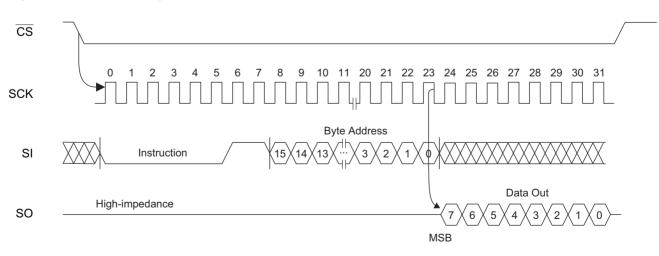


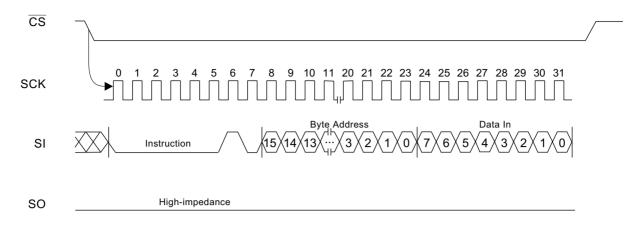


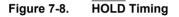


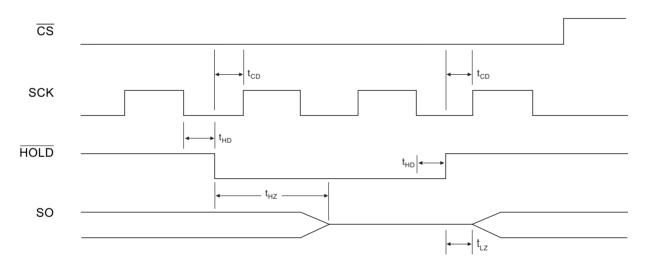


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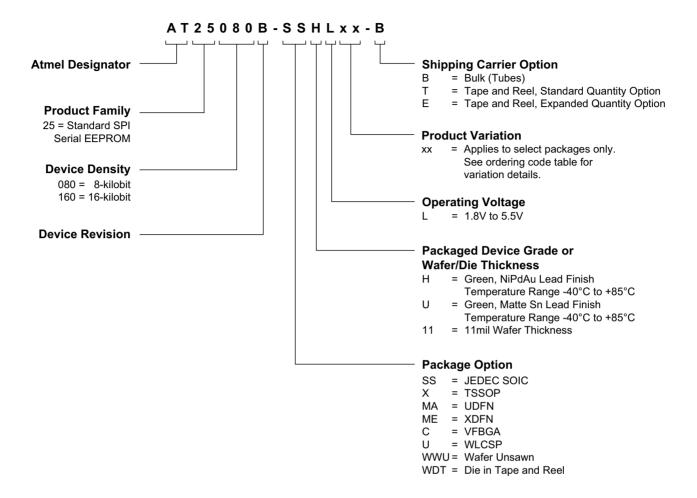








8. Ordering Code Detail



9. Part Markings

| | 8-lead SOIC | 8-lead TSSOP | 8-pad UDFN | | |
|--|--|---|--|---|--|
| | ATMLHYWW ###% AAAAAAAA | ATHYWW ###% @ AAAAAAA | 2.0 x 3.0 mm Body | @ | |
| | 8-pad XDFN | 8-ball VFBGA | 8-ball WLCSF | 8-ball WLCSP | |
| | 1.8 x 2.2 mm Body ### ¥XX € | 1.5 x 2.0 mm Body | .## | | |
| | Note 2: Package drawings are not to s | | | | |
| Catalog Number AT25080B AT25160B | r Truncation | Truncation Code ## Truncation Code ## | #: 5AB | | |
| AT25080B AT25160B Date Codes | | Truncation Code ## | #: 5AB Volta | - | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 5: 2015 9: 6: 2016 0: | M = Month2018A: January2019B: February20202021L: December | Truncation Code ## | #: 5AB Volta | ages % = Minimum Voltage L: 1.8V min | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 5: 2015 9: 6: 2016 0: | M = Month 2018 A: January 2019 B: February 2020 2021 L: December | Truncation Code ## | ##: 5AB Volta of Assembly | % = Minimum Voltage | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 5: 2015 9: 6: 2016 0: 7: 2017 1: | M = Month 2018 A: January 2019 B: February 2020 2021 L: Decembe embly | WW = Work Week 0 02: Week 2 04: Week 4 52: Week 52 | ##: 5AB Volta of Assembly Grac | % = Minimum Voltage L: 1.8V min | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 5: 2015 9: 6: 2016 0: 7: 2017 1: Country of Asse | M = Month 2018 A: January 2019 B: February 2020 2021 L: Decembe embly | Truncation Code ## | ##: 5AB Volta of Assembly Grac | % = Minimum Voltage L: 1.8V min de/Lead Finish Material | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 15: 2015 9: 16: 2016 0: 17: 2017 1: 17: 17: 17: 17: 17: 17: 17: 17: 17 | M = Month 2018 A: January 2019 B: February 2020 2021 L: Decembe embly | Truncation Code ## | ##: 5AB Volta of Assembly Grac umber Atm | % = Minimum Voltage L: 1.8V min de/Lead Finish Material H: Industrial/NiPdAu | |
| AT25080B AT25160B Date Codes Y = Year 4: 2014 8: 15: 2015 9: 16: 2016 0: 17: 2017 1: 17: 17: 17: 17: 17: 17: 17: 17: 17 | M = Month 2018 A: January 2019 B: February 2020 2021 L: December 2021 Assembly Assembly 2020 Atmel Lot Numbers Co | Truncation Code ## | ##: 5AB Volta of Assembly Grac umber Atm | % = Minimum Voltage L: 1.8V min de/Lead Finish Material H: Industrial/NiPdAu el Truncation AT: Atmel M: Atmel | |

Atmel

10. Ordering Information

| | | | Delivery Information | | Operation |
|---------------------------------|------------------------------------|------------|----------------------|-----------------|--|
| Atmel Ordering Code | Lead Finish | Package | Form | Quantity | Range |
| AT25080B-SSHL-B | | 8S1 | Bulk (Tubes) | 100 per Tube | |
| AT25080B-SSHL-T | - | 001 | Tape and Reel | 4,000 per Reel | |
| AT25080B-XHL-B | _ | 8X | Bulk (Tubes) | 100 per Tube | |
| AT25080B-XHL-T | NiPdAu (Lead-free/Halogen-free) | 0 | Tape and Reel | 5,000 per Reel | |
| AT25080B-MAHL-T | | 8MA2 | Tape and Reel | 5,000 per Reel | Industrial |
| AT25080B-MAHL-E | - | 8MA2 | Tape and Reel | 15,000 per Reel | Temperature (-40 to 85°C) |
| AT25080B-MEHL-T | - | 8ME1 | Tape and Reel | 5,000 per Reel | |
| AT25080B-CUL-T | SnAgCu | 8U3-1 | Tape and Reel | 5,000 per Reel | |
| AT25080B-UUL0B-T ⁽¹⁾ | (Lead-free/Halogen-free) | 8U-12 | Tape and Reel | 5,000 per Reel | |
| AT25080B-WWU11L ⁽²⁾ | N/A | Wafer Sale | Note 2 | | |
| AT25160B-SSHL-B | | | Bulk (Tubes) | 100 per Tube | |
| AT25160B-SSHL-T | _ | 8S1 | Tape and Reel | 4,000 per Reel | |
| AT25160B-XHL-B | _ | | Bulk (Tubes) | 100 per Tube | |
| AT25160B-XHL-T | NiPdAu | 8X | Tape and Reel | 5,000 per Reel | |
| AT25160B-MAHL-T | (Lead-free/Halogen-free) | 8MA2 | Tape and Reel | 5,000 per Reel | Industrial Temperature (-40 to 85°C) |
| AT25160B-MAHL-E | _ | | Tape and Reel | 15,000 per Reel | |
| AT25160B-MEHL-T | _ | 8ME1 | Tape and Reel | 5,000 per Reel | (10 10 00 0) |
| AT25160B-CUL-T | SnAgCu | 8U3-1 | Tape and Reel | 5,000 per Reel | |
| AT25160B-UUL0B-T ⁽¹⁾ | (Lead-free/Halogen-free) | 8U-12 | Tape and Reel | 5,000 per Reel | |
| AT25160B-WWU11L ⁽²⁾ | N/A | Wafer Sale | · · | ote 2 | |

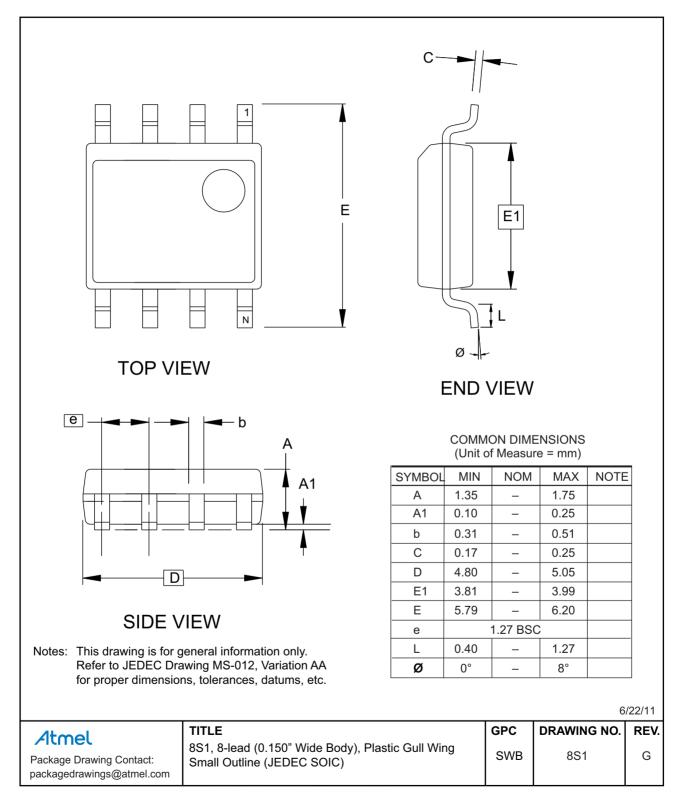
Notes: 1. WLCSP Package:

- This device includes a backside coating to increase product robustness.
- CAUTION: Exposure to ultraviolet (UV) light can degrade the data stored in the EEPROM cells. Therefore, customers who use a WLCSP product must ensure that exposure to ultraviolet light does *not* occur.
- 2. Contact Atmel Sales for Wafer sales.

| | Package Type |
|-------|--|
| 8S1 | 8-lead, 0.150" wide, Plastic Gull Wing Small Outline (JEDEC SOIC) |
| 8X | 8-lead, 4.4mm body, Plastic Thin Shrink Small Outline Package (TSSOP) |
| 8MA2 | 8-pad, 2.0mm x 3.0mm x 0.6mm body, Thermally Enhanced Plastic Ultra Thin Dual Flat Dual No Lead (UDFN) |
| 8ME1 | 8-pad 1.8mm x 2.2mm body, Extra Thin DFN (XDFN) |
| 8U3-1 | 8-ball, 1.50mm x 2.00mm body, 0.50mm pitch, Very Thin, Fine-Pitch Ball Grid Array (VFBGA) |
| 8U-12 | 8-ball, 5 x 3 grid array, 0.40mm pitch, Wafer Level Chip Scale Package (WLCSP) |

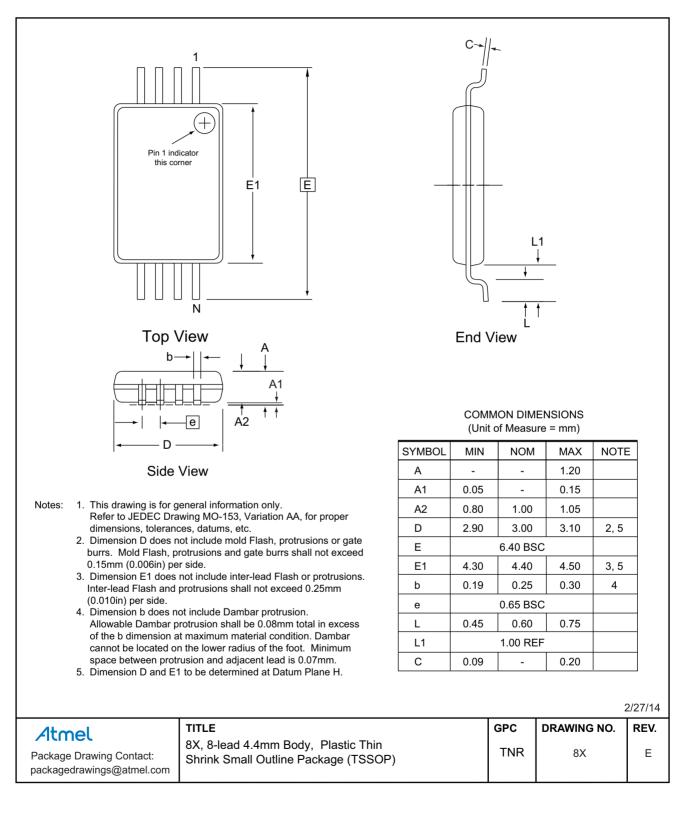
11. Packaging Information

11.1 8S1 — 8-lead JEDEC SOIC



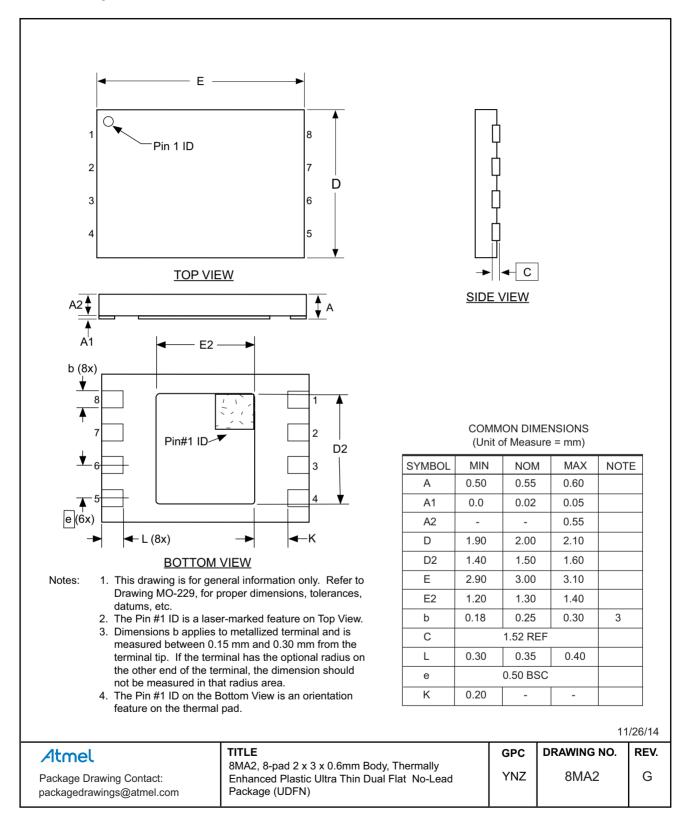


11.2 8X — 8-lead TSSOP



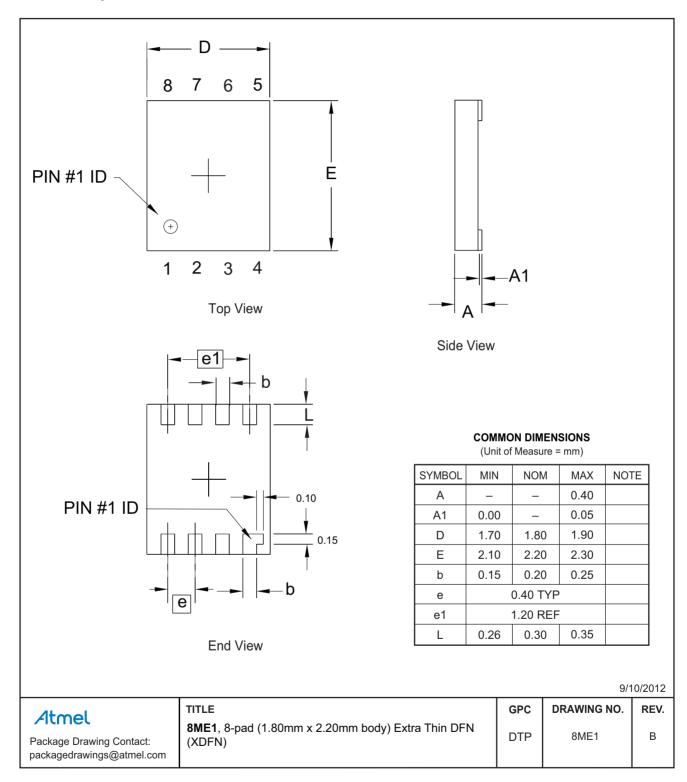
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11.3 8MA2 — 8-pad UDFN

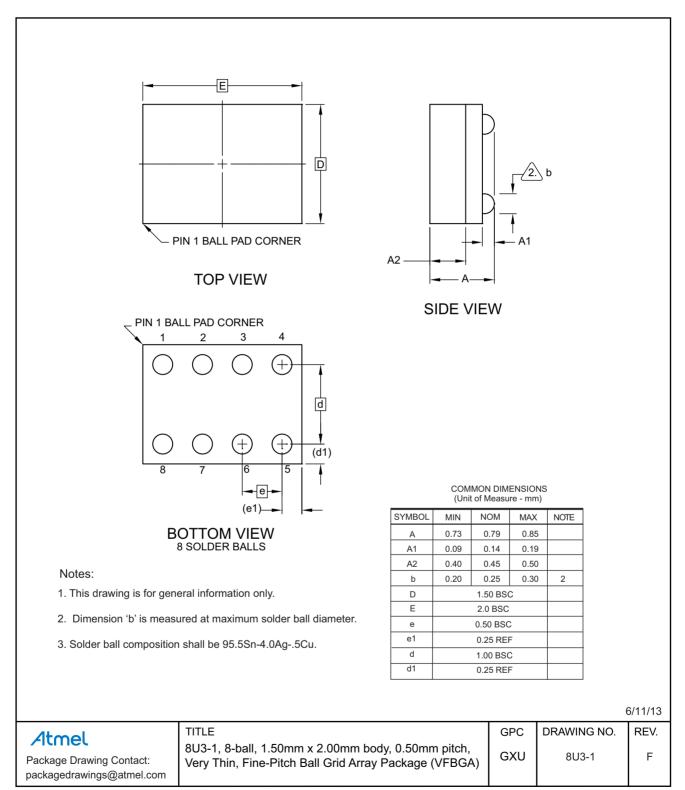


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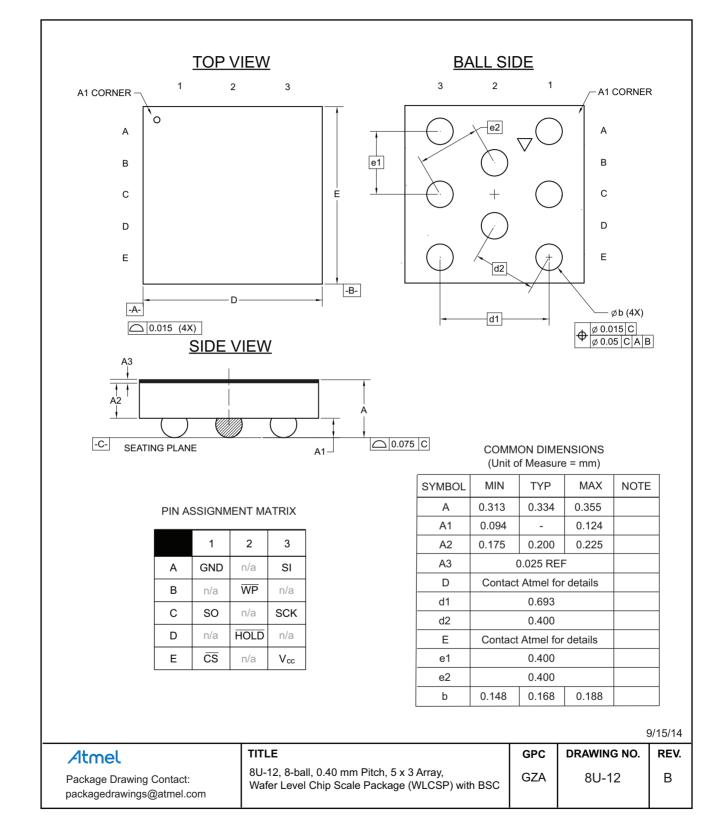
11.4 8ME1 — 8-pad XDFN



11.5 8U3-1 — 8-ball VFBGA



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11.6 8U-12 - 8-ball WLCSP

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12. Revision History

| Doc. Rev. | Date | Comments |
|-----------|---------|--|
| 5228G | 01/2015 | Add the AT25080B-MAHL-E and AT25160B-MAHL-E package options. Update the 8MA2 and 8U-12 package drawings and the ordering information. |
| 5228F | 07/2014 | Add WLSCP package option. Update 8X, 8MA2, 8ME1, and 8U3-1 package drawings. Update template, Atmel logos, disclaimer page. |
| 5228E | 03/2012 | Update 8A2 to 8X and 8S1, 8MA2, 8U3-1 package drawings. |
| 5228D | 04/2010 | Update Ordering Code Detail and Ordering Information. |
| 5228C | 08/2009 | Change Catalog Scheme and add Marking Details. |
| 5228B | 07/2008 | Change 'Endurance' parameter on page 6. |
| 5228A | 09/2007 | Initial document release. |



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 AT25080B-XHL-T
 AT25160B

 MAHL-T
 AT25160B-SSHL-B
 AT25160B-SSHL-T
 AT25160B-XHL-B
 AT25160B-XHL-T
 AT25080B-TH-B
 AT25160B

 TH-T
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